

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

2/87

Eugene H. Cloud

Title:

HIGH DENSITY STORAGE SCHEME FOR SEMICONDUCTOR MEMORY

Docket No.:

303.663US1

Filed: Examiner: March 3, 2000 Than Nguyen

Serial No.: 09/518338 Due Date: May 28, 2003

Group Art Unit: 2187

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Technology Center 2100

MS Non-Fee Amendment

Commissioner for Patents

P.O.Box 1450

Alexandria, VA 22313-1450

We are transmitting herewith the following attached items (as indicated with an "X"):

A return postcard.

An Amendment and Response (11 Pages).

, If not provided for in a separate paper filed herewith, Please consider this a PETITION FOR EXTENSION OF TIME for sufficient number of months to enter these papers and please charge any additional fees or credit overpayment to Deposit Account No. 19-0743.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

P.O. Box 2938, Minneapolis, MN 55402 (612-373-6900)

Atty: Viet V. Tong Reg. No. 45,416

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CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: MS Non-Fee Amendment, Commissioner for Patents, P.O.Box 1450, Alexandria, VA 22313-1450, on this 25 day of May, 2003.

Gina M. Uphus

Name

Customer Number 21186

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(GENERAL)

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ES/N 09/518338

PATENT

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Applicant:

Eugene H. Cloud

Examiner: Than Nguyen

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HIGH DENSITY STORAGE SCHEME FOR SEMICONDUCTOR MEMORY

AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111

Commissioner for Patents P.O.Box 1450 Alexandria, VA 22313-1450

Applicant has reviewed the Office Action mailed on <u>February 28, 2003</u>. Please consider the following remarks.

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